Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	2468	amorphiz$6 or amorphor$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 13:49
L2	5872	noncrystal$10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 13:50
L3	12455	1 or 2 or alpha near2 (silicon or semiconductor or si)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 13:51
L4	756301	laser	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 13:51
L5	7242	spc or solid adj phacse adj crystal$10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:39
L6	158963	ldd or light$4 adj dope$4 adj drain or shallow	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 13:52
L7	24712	ldd or light$4 adj dope$4 adj drain or shallow near2 (source or drain or junction or ultra)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:14
L8	0	7 same 5 same 3 same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:39
L9	15	7 and 5 and 3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:39
L10	4	5 same 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:00

L11	25	5 same 6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:09
L12	200877	mosfet or (metal adj (oxide or insulat$$) adj semiconducor adj (fet or field)) or pmos or cmos or nmos or misfet	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:08
L13	112	12 and 7 and 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:10
L14	2	12 and 7 same 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:10
L15	18499	ldd or light$4 adj dope$4 adj drain or low adj densit$4 adj dop$5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:14
L16	1079	ultrashallow or ultra adj shallow	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:42
L17	3	(15 or 16) same 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:04
L18	153	(15 or 16) and 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:26
L19	1	16 and 5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:28
L20	5722	shallow near2 junction	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:38

L21	7985	spc or solid adj phase adj crystal$10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:39
L22	0	7 same 21 same 3 same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:39
L23	22	7 and 21 and 3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:40
L24	7	23 not 9	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:40
L25	0	16 same 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:49
L26	4	16 and 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:51
L27	145368	shallow	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:52
L28	23	27 same 21	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 14:52
L29	570	(15 or 16) same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:04
L30	308	29 and 12	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:05

L31	1347608	crystal$10 or recrystal$10 or polycrystal$10	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:05
L32	121	29 not 31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:07
L33	21	29 same 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:07
L34	1	33 not 31	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:07
L35	145415	ultrashallow or shallow	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:43
L36	35	35 same 3 same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:54
L37	103	35 same 3 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 15:45
L38	3	(("6326226") or ("6608326") or ("6821825")).PN.	USPAT	OR	OFF	2004/11/23 15:53
L39	0	38 same 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:46
L40	3095	((438/303) or (438/482) or (438/484) or (438/520) or (438/522) or (438/528)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/23 17:45

L41	839	((438/482) or (438/484)).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2004/11/23 17:46
L42	37	41 and 27	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:47
L43	8	41 and 27 and 4	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 17:47

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	7616	spc or solid adj phase adj crystallization	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 11:54
L2	1455	silicon and 1	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 11:55
L3	199	germanium and 2	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 11:58
L4	105	cmos and 3	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/11/23 11:59